# Angular dependence of critical currents in YBCO coated conductors and thin films

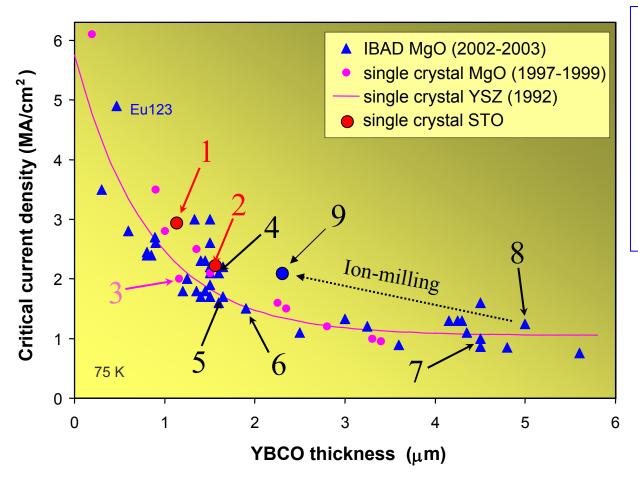
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# The J<sub>c</sub> of PLD YBCO films on polycrystalline Ni-alloy using IBAD MgO is equivalent to that of films on single-crystal substrates (at 75K, self field)



#### Implication:

- •J<sub>c</sub> limited by bulk vortex pinning
- •Uniform current flow

as opposed to

- •J<sub>c</sub> limited by weak links
- Percolative paths
- •Non uniform current flow

What happens as a function of temperature and magnetic field?





# What can we learn from the field, angular and temperature dependence of J<sub>c</sub>?

#### •Immediate goals:

- ✓ Identification of pinning sources (correlated vs. uncorrelated defects, etc)
- ✓ Comparison of CC made by different routes and films on single crystals Are pinning mechanisms the same ? (High quality CC available from various sources)

#### •Long term goals:

Can we improve in-field  $J_c$  by appropriate engineering of defects?

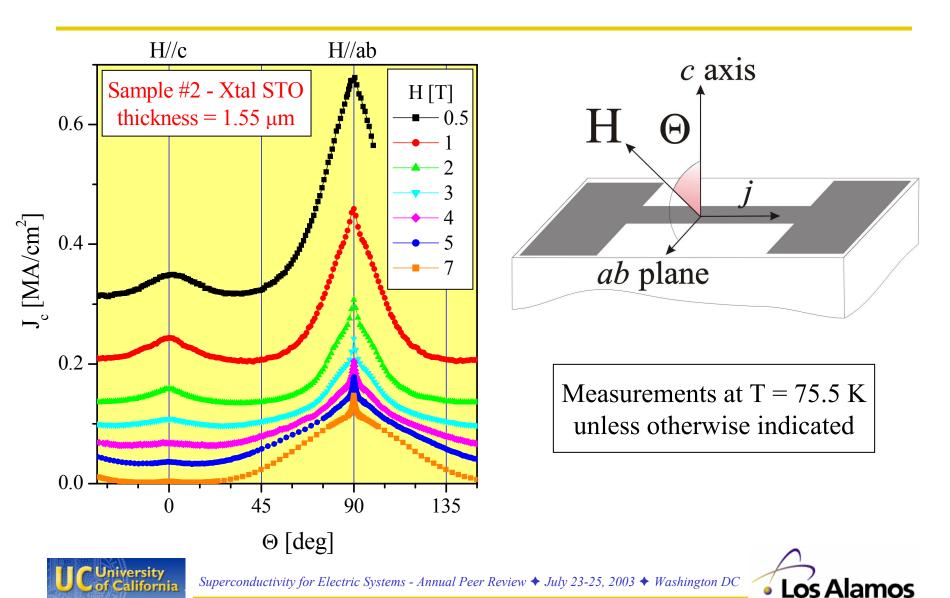
#### •Questions:

- ✓ How reproducible is  $J_c(H,Θ)$  for a given fabrication process?
- ✓ What is a "standard" or "reference" sample?
- ✓ Which are the useful characterization parameters?

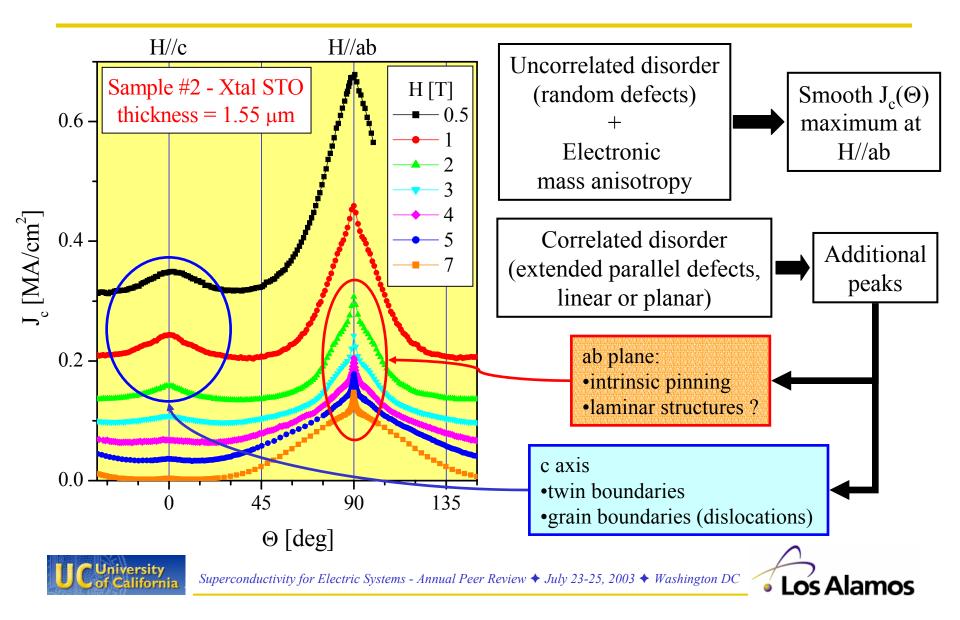




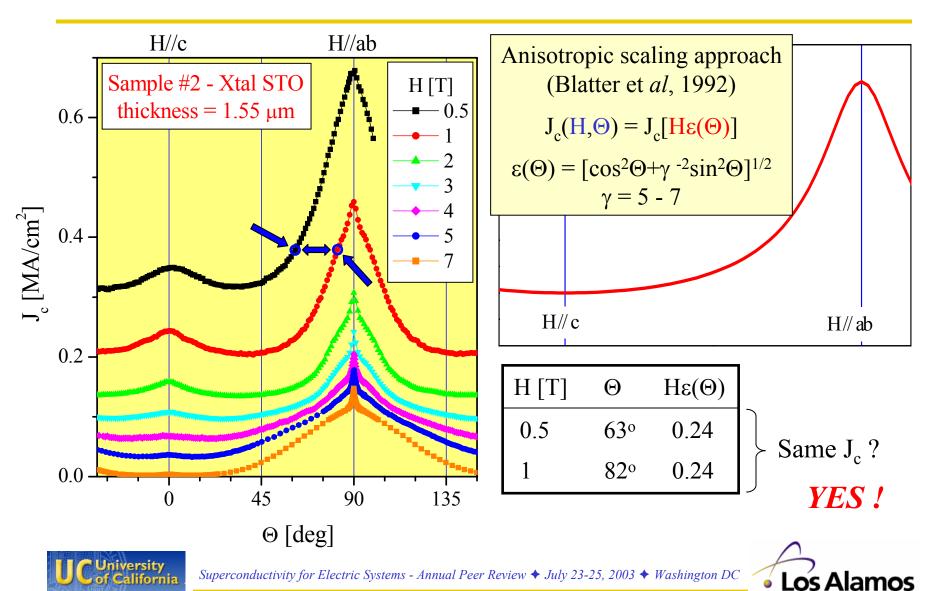
### Measurements of the angular dependence of J<sub>c</sub>



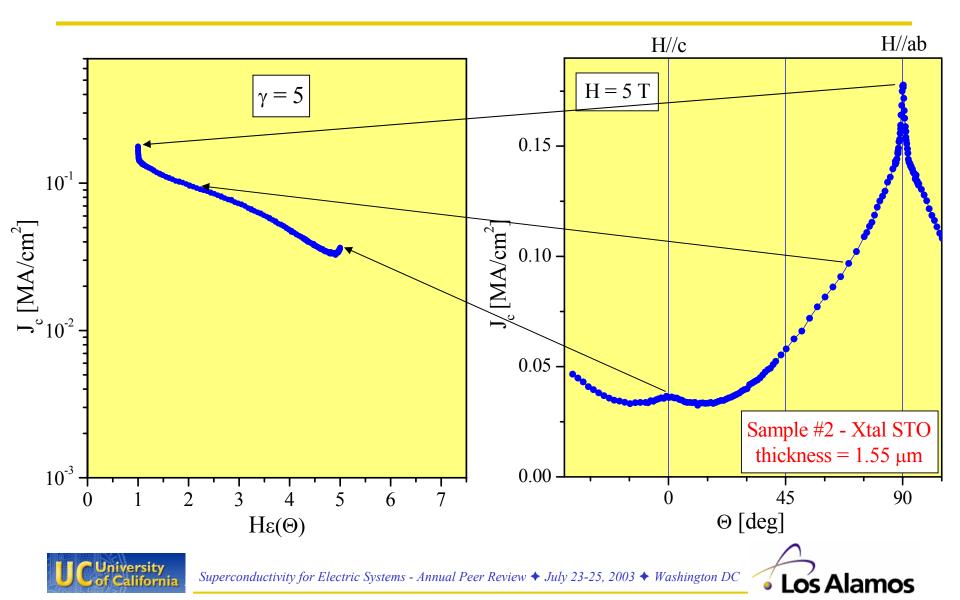
# The angular dependence of J<sub>c</sub> arises from a combination of factors and exhibits various regimes



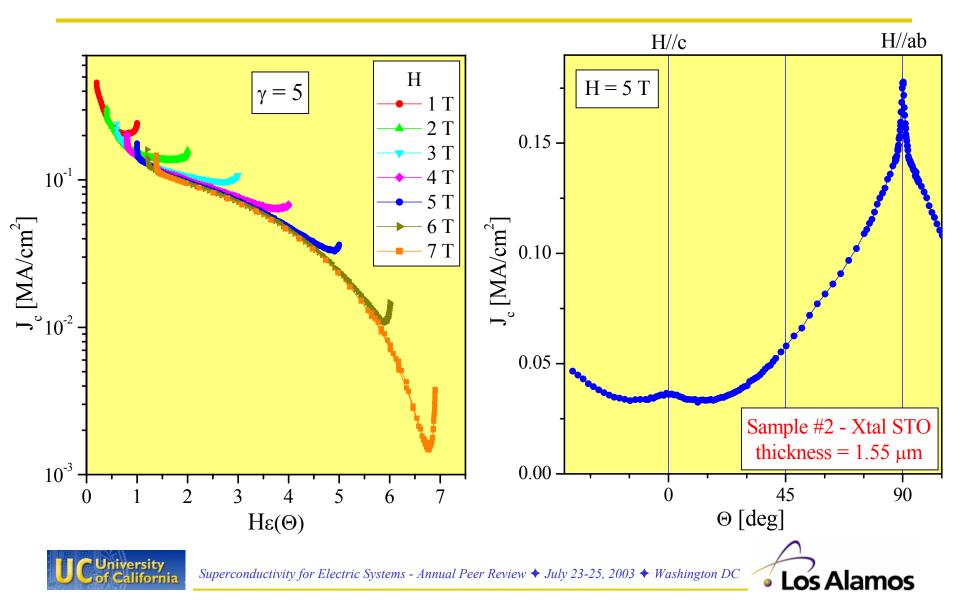
# Pinning by uncorrelated disorder (random defects): influence of electronic mass anisotropy



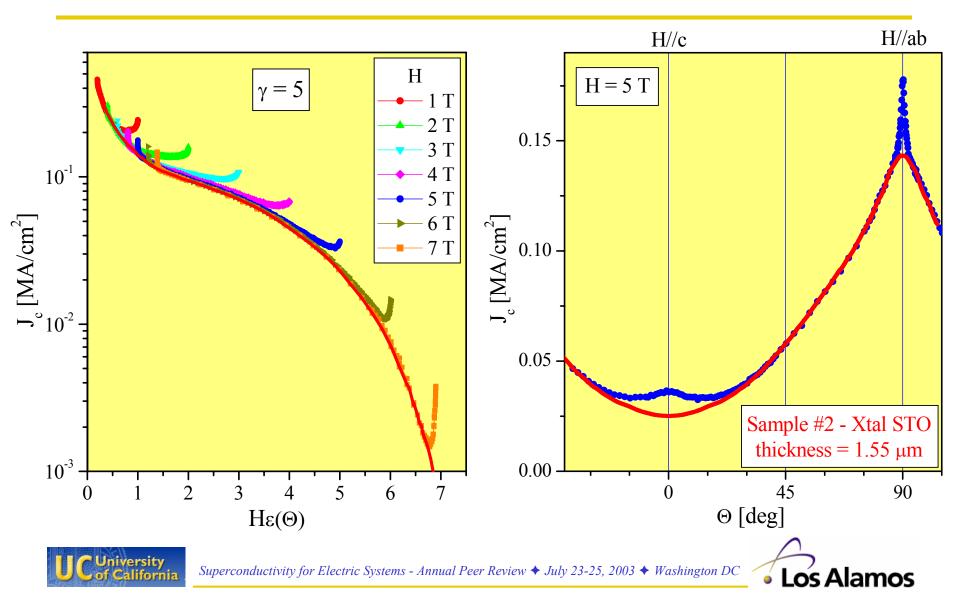
### Contribution of the uncorrelated disorder to J<sub>c</sub>



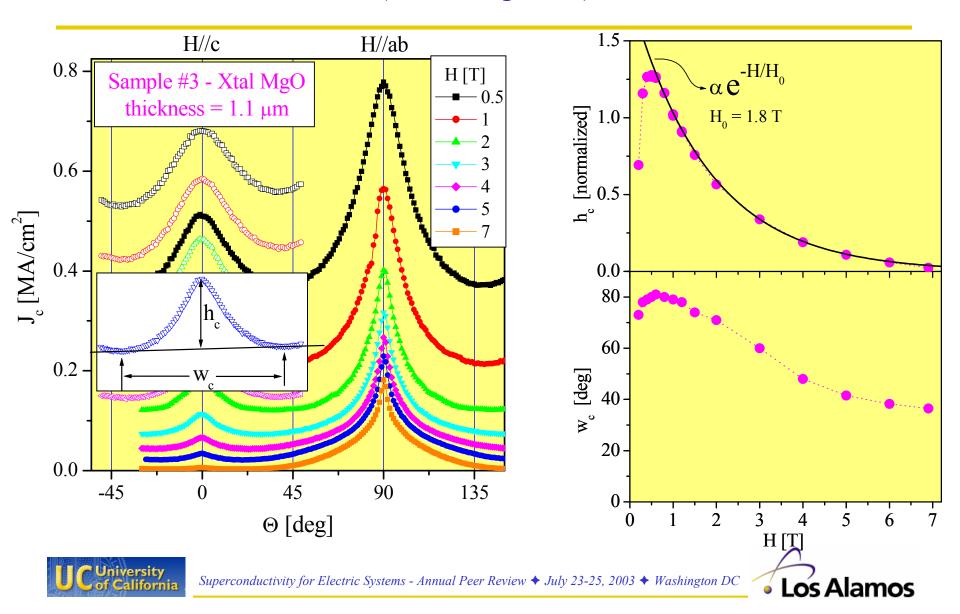
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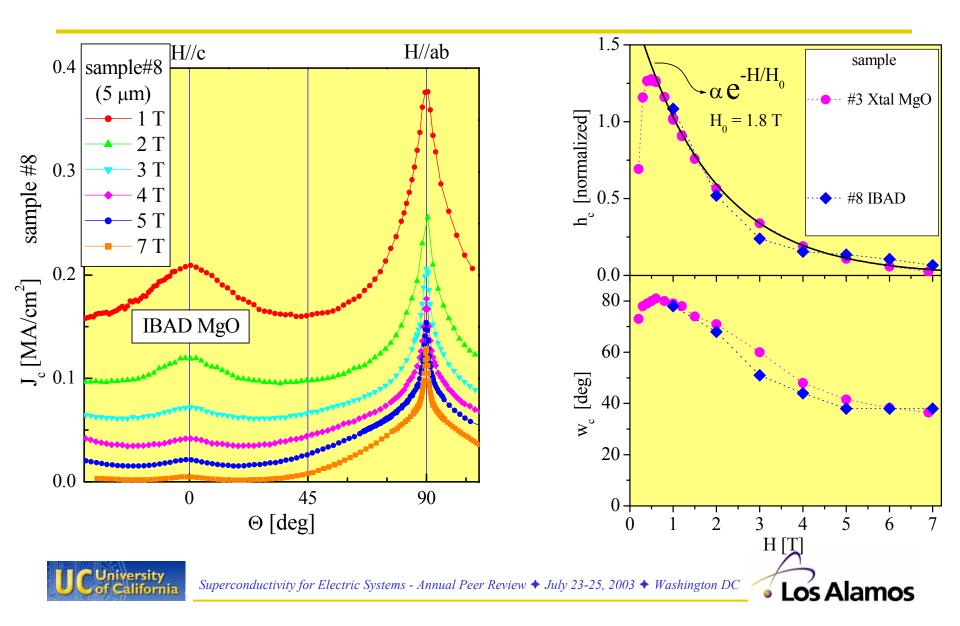
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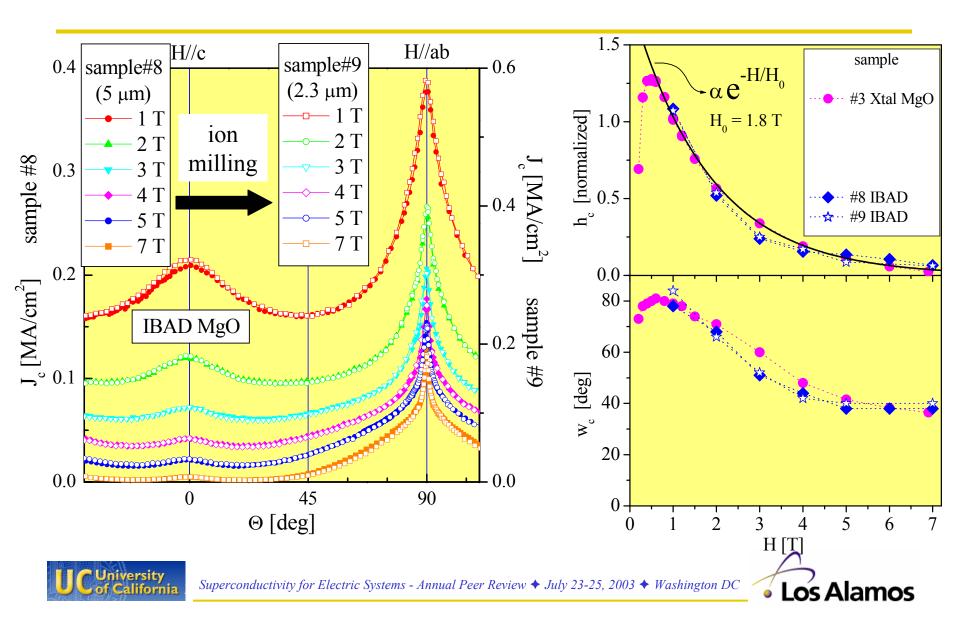
# c axis peak: directional pinning by correlated disorder (linear or planar)



#### Field dependence of c axis peak for IBAD MgO samples



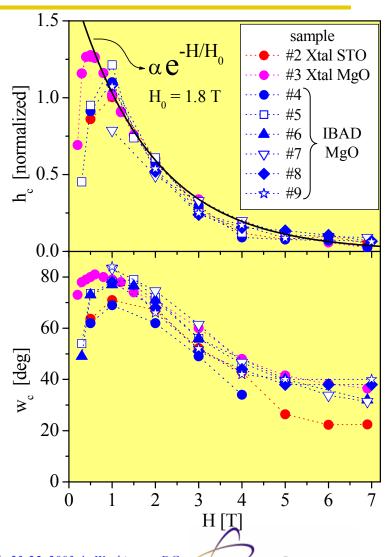
### Field dependence of c axis peak for ion-milled IBAD MgO sample



### Field dependence of c axis peak for different samples

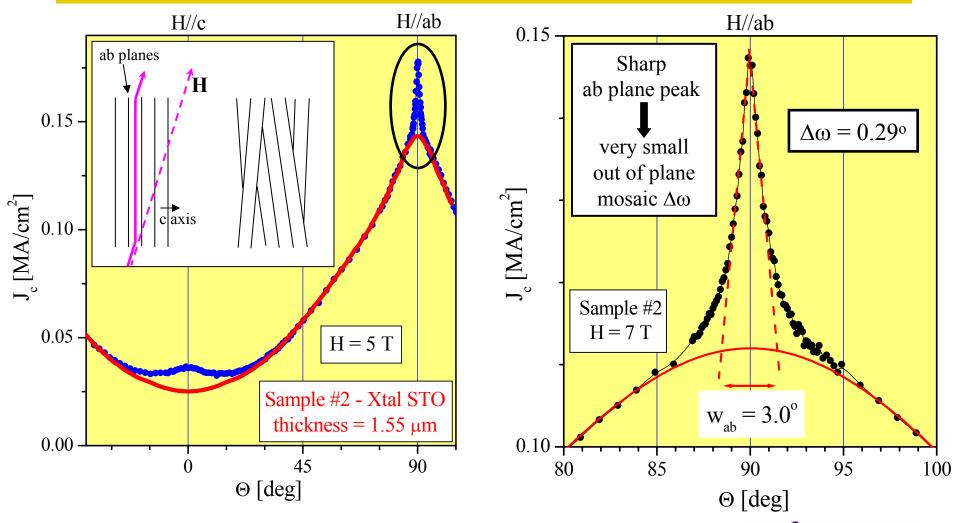
The height and width of the c axis peak have essentially the same field dependence for 8 films on STO and MgO single crystal and IBAD MgO templates, with thickness ranging from 1 to 5 µm, including one ion-milled sample

- The same type of correlated defects must be acting in all cases
- The difference in height indicates variations in defect density
- Crossover observed at  $H \sim 1 T$





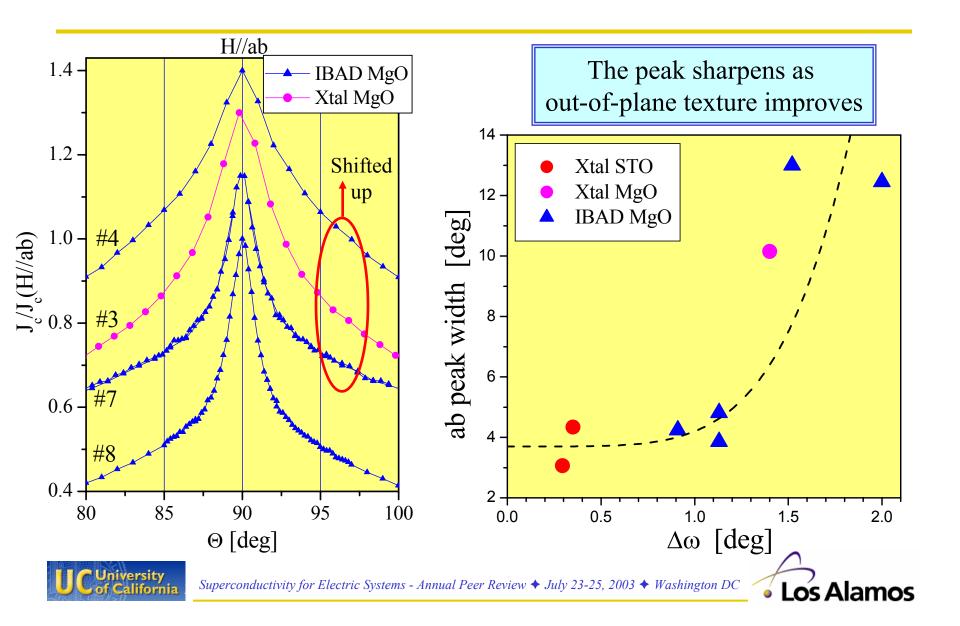
#### Intrinsic pinning peak at the ab planes







#### The intrinsic pinning peak is visible in all films



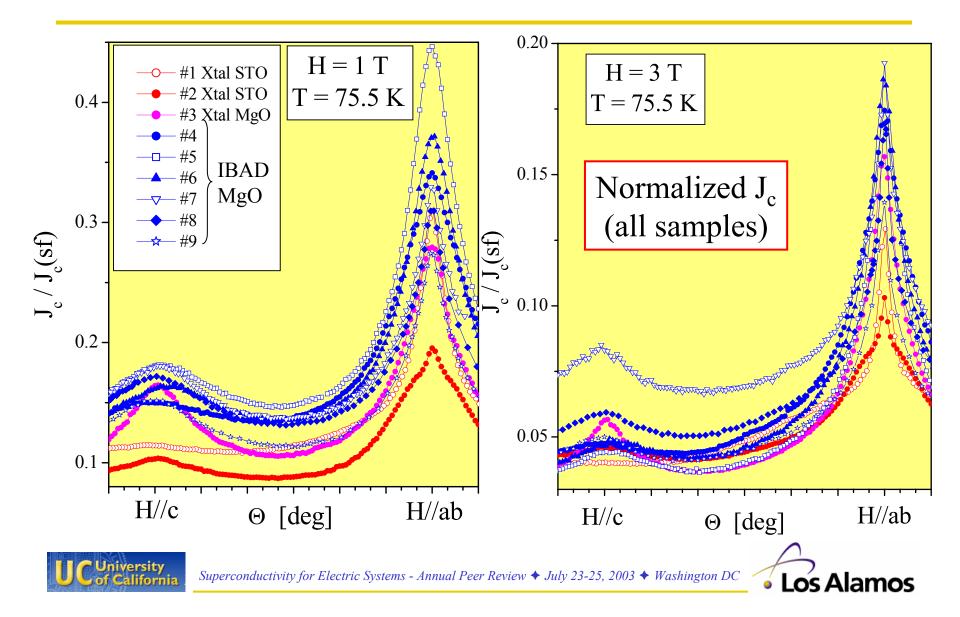
#### Summary so far

- •Reproducibility among samples made by the same process is good.
- •Samples of different type have overall similar angular dependence.
- •The main sources of vortex pinning and the various angular regimes were identified.
  - •The angular dependence of the contribution of random defects to  $J_c$  can be described using an anisotropic scaling approach.
  - •The c axis peak arising from correlated disorder such as twins and grain boundaries was characterized. Both the angular width and the normalized amplitude of the peak follow an universal field dependence for PLD YBCO.
  - •An additional ab plane peak due to intrinsic pinning appeared in all measured samples. The peak sharpens as the out-of-plane texture of the film  $(\Delta \omega)$  decreases.



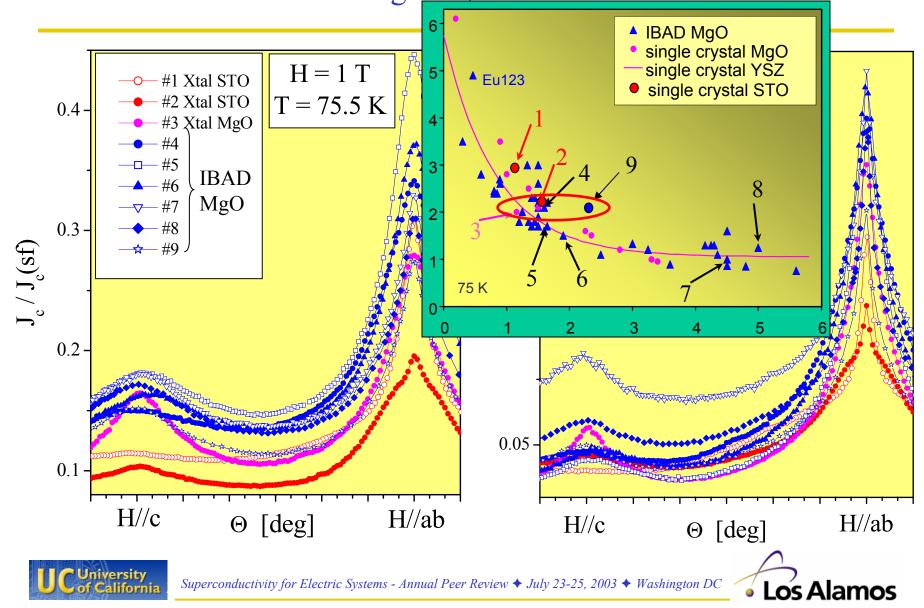


# Comparison of $J_c(H,\Theta)$ for PLD YBCO films on IBAD MgO and on single crystal substrates

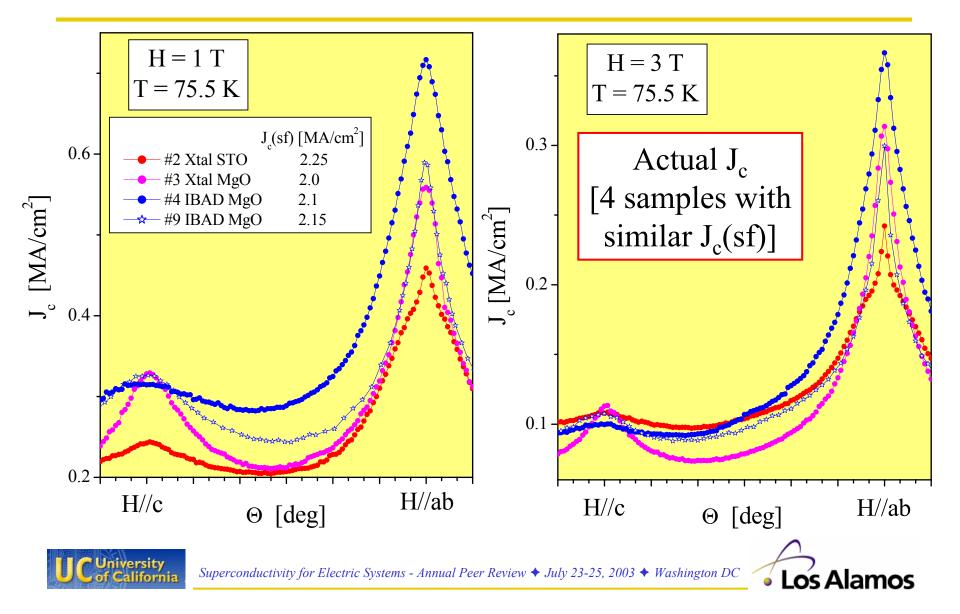


Comparison of J<sub>c</sub>(H,Θ) for PLD YBCO films on IBAD MgO

and on single crystal substrates



# Comparison of $J_c(H,\Theta)$ for PLD YBCO films on IBAD MgO and on single crystal substrates



#### Conclusions

- •The PLD YBCO / IBAD MgO coated conductors have HIGHER J<sub>c</sub> than the films on single crystals over extensive ranges of magnetic field intensity and orientation. The extra pinning probably arises from:
  - Additional random defects (larger RBS reflectivity)
  - •Additional c axis correlated defects:
    - More screw dislocations at low-angle grain boundaries.
    - Slightly higher in-plane mosaic  $\Delta \phi$ .
    - Sub-grain structures.
  - •Additional correlated structures parallel to the ab planes (higher out-of-plane  $\Delta\omega$ )
- •There is room for further pinning improvement in CC through microstructural engineering.
- •Pinning optimization will be application dependent.



